

GMN080B06D GOOD-ARK Electronics

N-Channel 60V (D-S) Power MOSFET

Features

- 100% Avalanche Tested
- Extremely Low Losses with Low FOM Rdson*Qg
- Halogen Free, Pb-Free
- RoHS Compliant

Applications

- DC/DC
- Motors, lamps
- Power switching

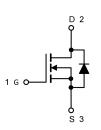
Absolute Maximum Ratings (TJ=25°C unless otherwise noted)						
Parameter		Symbol	Value	Unit		
Drain Source Voltage		V _{DS}	60	V		
Gate Source Voltage		V_{GS}	±20	V		
Drain Current, Continuous V _{GS} =10V <i>(Note 1)</i>	T _C =25°C	I _D	80	А		
Drain Current, Pulsed (Note 2)		I _{DM}	320	А		
Single Avalanche Energy@ L=0.5mH		E _{AS}	210	mJ		
Power Dissipation(Note 3)	T _c =25°C	Po	74	W		
Operating Junction/ Storage Temperature Range		TJ/ T _{STG}	T _{STG} -55 to +150			

Note 1: Calculated continuous current based on maximum allowable junction temperature. Note 2: Repetitive rating; pulse width limited by max. junction temperature.

Thermal Characteristics						
Parameter	Symbol	Мах	Unit			
Thermal Resistance Junction to Case(Note 3)	R _{thJC}	1.7	°C/W			

Note 3: The power dissipation PD is based on max. junction temperature, using junction-to-case thermal resistance







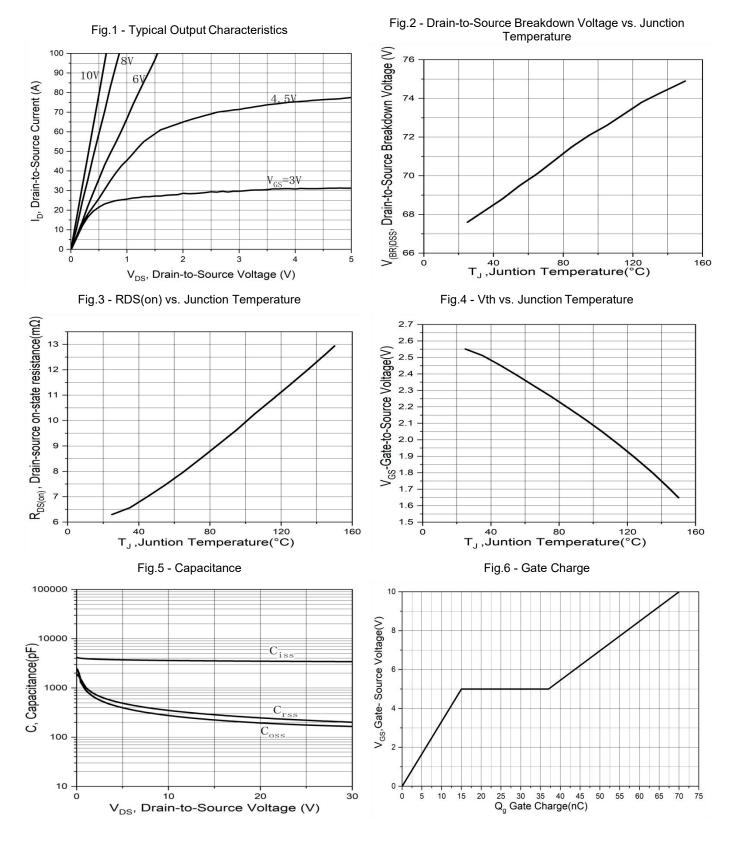
Electrical Characteristics (T _J =25°C unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Drain Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250µA	60			V
Zero Gate Voltage Drain Current	IDSS	V _{DS} =60V, V _{GS} =0V			1	uA
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _{DS} =250uA	2		4	V
Gate Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V			±100	nA
Drain-Source On-state Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A		6.3	8	mΩ
Total Gate Charge	Qg	I _D = 20A, V _{DS} =30V, V _{GS} = 10V		70		
Gate-Source Charge	Q _{gs}			15		nC
Gate-Drain Charge	Q _{gd}			22		
Turn-on Delay Time	t _{d(on)}	$V_{GS}=10V, V_{DD}=30V, \\ R_{GEN}=3\Omega, \\ I_{D}=30A$		15		
Turn-on Rise Time	tr			22		
Turn-off Delay Time	t _{d(off)}			40		ns
Turn-off Fall Time	t _f			8.6		
Input Capacitance	C _{iss}	V _{GS=} 0V, V _{DS} =60V, f=1MHz		3450		
Output Capacitance	Coss			180		pF
Reverse Transfer Capacitance	Crss			165		

Reverse Diode Characteristics (T _J =25°C unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Continuous Source Current (Body Diode)	ls	T _C =25°C			80	A
Pulsed Source Current (Body Diode)	I _{SM}				320	
Diode Forward Voltage	V _{SD}	I _S =20A, V _{GS} =0V			1.2	V
Reverse Recovery Time	T _{rr}	I _F =20A, di/dt = 100 A/μs		25		ns
Reverse Recovery Charge	Qrr			30		nC



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Typical Characteristics Curves (T_J = 25°C unless otherwise noted)





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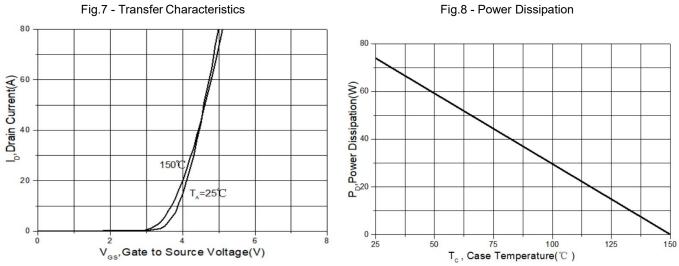
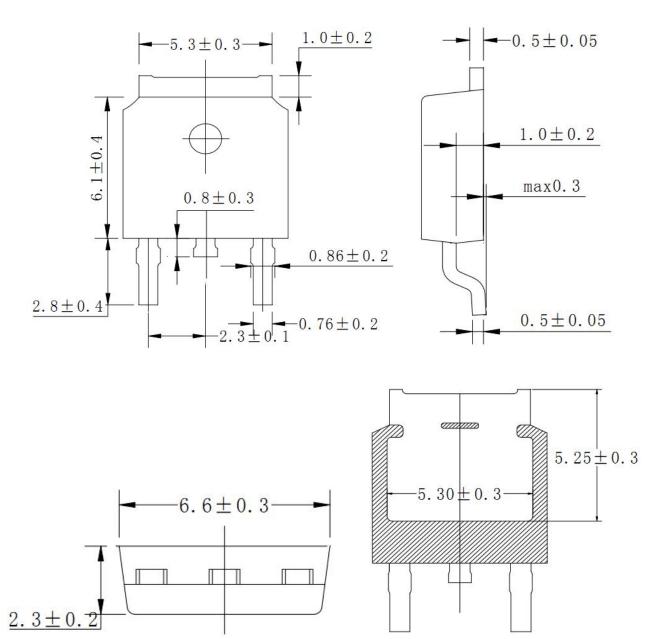


Fig.8 - Power Dissipation



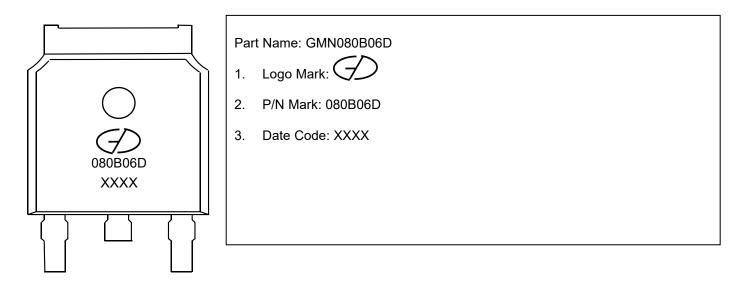
Package Outline Dimensions (Unit: millimeters)

TO-252(D-PAK)





Marking Outline





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